Kondo-induced giant isotropic negative thermal expansion


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Negative thermal expansion is an unusual phenomenon appearing in only a handful of materials, but pursuit and mastery of the phenomenon holds great promise for applications across disciplines and industries. Here we report use of X-ray spectroscopy and diffraction to investigate the $4f$-electronic properties in Y-doped SmS and employ the Kondo volume collapse model to interpret the results. Our measurements reveal an unparalleled decrease of the bulk Sm valence by over 20% at low temperatures in the mixed-valent golden phase, which we show is caused by a strong coupling between an emergent Kondo lattice state and a large isotropic volume change. The amplitude and temperature range of the negative thermal expansion appear strongly dependent on the Y concentration and the associated chemical disorder, providing control over the observed effect. This finding opens new avenues for the design of Kondo lattice materials with tunable, giant and isotropic negative thermal expansion.

The surprising physical property of some solids to contract upon heating, referred to as negative thermal expansion (NTE), has been documented for over a century [1]. During the past two decades, synthesis discoveries have been greatly accelerated and have identified materials with strong NTE over wide temperature ranges, boosting the potential for practical integration in state-of-the-art technologies such as high-precision optics, electronics and optoelectronics, where thermal stresses and dimensional stability present performance limitations [2, 3]. Despite rapid advances in documenting the gamut of mechanisms underpinning NTE, detailed understanding of the mechanisms, and the extent to which they can be enumerated is still under debate, but many NTE materials appear to feature phase transformation under very light pressure, suggestive that NTE is a consequence of fluctuations as is observed, for example, in water at temperatures 4 K above the freezing point [4, 5].

Seemingly unrelated to the physics of the NTE, the Kondo impurity effect traces back over half a century with the observation of a minimum in the resistivity of metals which was identified as due to spin-flip scattering of conduction electrons from magnetic impurities through an interaction that effectively screens their local magnetic moments at low temperature [6]. In $f$-electron systems, the effective Kondo interaction is brought about by hybridization between localized $f$-electrons and the delocalized conduction states, and underpins the emergence of a coherent lattice behavior and associated gap at low temperatures. Although the Kondo screening is accompanied by a change of the net $f$-shell occupancy upon cooling, the increase is usually just on the order of $\sim 1 - 2\%$ [7] and has an accordingly small effect on the thermal expansion characteristics.

An exceptional occurrence of strong, isotropic, thermally robust and tunable NTE has recently been reported in the Kondo material Sm$_{1-x}$Y$_x$S [8]. SmS is a black-colored (b) semiconductor which undergoes a first-order isostructural volume collapse transition into a gold-colored (g) metallic state through chemical pressure by substitution of Sm with Y [9-11]. This golden phase ($x \geq 17\%$), which had already gained attention early on for showing a negative Poisson’s ratio [12], has recently
garnered renewed interest, in particular for a potential topological transition in the Fermi surface as the intermediate valence monotonically decreases upon cooling [13–17]. Using advanced synchrotron X-ray tools to precisely determine $n_f$ and the lattice constant, and aided by a theoretical analysis based on the Kondo volume collapse (KVC) [18] and the two-fluid model [19], we show that the golden phase at low temperatures is characterized by an unusually strong increase in $n_f$ which couples with the lattice through a KVC. This effect culminates in a giant NTE, contrary to elemental Cerium where the KVC model was originally developed to describe the strong positive thermal expansion. The Y substitution produces first-order valence and lattice transitions locally but the induced disorder results in an effectively broadened transition on macroscopic scales, which ultimately weakens the NTE behavior as these macroscopic effects are exacerbated for higher Y concentrations. The finding of an NTE driven by Kondo screening suggests that materials where hybridization between predominantly localized and itinerant electronic degrees of freedom provide promising opportunities for the realization of a new class of single-phase, isotropic and iso-structural giant NTE systems, tunable through application of pressure and/or alloying.

**EXPERIMENTAL RESULTS**

Figure 1 shows the temperature dependence of the unit cell volume of unsubstituted $b$–SmS, the black 17% system $b$–Sm$_{0.83}$Y$_{0.17}$S, the golden 17% system $g$–Sm$_{0.83}$Y$_{0.17}$S and $g$–Sm$_{0.67}$Y$_{0.33}$S. While the unit cell volumes of $b$–SmS and $b$–Sm$_{0.83}$Y$_{0.17}$S show conventional positive thermal expansion with a relative change of $\sim 0.6\%$ between 10 and 300 K, NTE is observed in the golden phase, with marked increases in the unit cell volume of 5% and 1.5% for $g$–Sm$_{0.83}$Y$_{0.17}$S and $g$–Sm$_{0.67}$Y$_{0.33}$S respectively, in agreement with a recent study [3].

The microscopic origin of NTE in golden SmS was studied via X-ray absorption spectroscopy in the partial fluorescence yield mode (PFY-XAS), which enables us to estimate the temperature and Y-substitution dependence of the Sm valence with a higher accuracy than conventional XAS [22]. The experimental data, shown in Figure 2A along with some representative fits, reveal two main peaks corresponding to $2p \rightarrow 5d$ dipolar excitations for divalent and trivalent Sm states. The Sm valence, $v$, is derived from the relative intensity of these two peaks. Nearly invariant in the black phase, the valence undergoes a sharp increase right at the black-to-gold transition at $x = 0.17$, which is expected from the volume collapse. The key experimental result of this study is the observation of a gradual but pronounced decrease of the valence upon cooling in the golden phase, down to $v = 2.257$ in $g$–Sm$_{0.83}$Y$_{0.17}$S, indicating that, remarkably, the system reverts to a nearly divalent state at low temperatures. The valence decrease is noticeably weaker in $g$–Sm$_{0.67}$Y$_{0.33}$S, for which the low-temperature value is $v = 2.32$. The behavior of the valence in the golden phase seems to be directly linked to NTE, as the system with the largest valence change, $g$–Sm$_{0.83}$Y$_{0.17}$S, also shows the largest NTE effect.

The valence decrease by $\sim 0.2$ in $g$–Sm$_{0.83}$Y$_{0.17}$S at low temperatures is stronger by about an order of magnitude than the typical valence change displayed by Kondo materials, which are most often Ce or Yb-based [7, 21–24]. Particularly interesting is the comparison with an Sm-based Kondo system that has recently drawn a lot of interest, SmB$_6$, and which is also in the strongly intermediate-valence regime. SmB$_6$ features a nearly zero thermal expansion while the valence decreases only by $\sim 0.07$ electrons, which is considered quite strong in comparison to many Kondo-screened materials [13, 25–30]. This comparison further hints at an additional effect in low-temperature golden Sm$_{1-x}$Y$_x$S, beyond the usual Kondo crossover, contributing to the unconventional strong electron localization disclosed by the PFY-XAS data.

In fact, the strong coupling between the large changes in the charge and lattice degrees of freedom in Sm$_{1-x}$Y$_x$S is reminiscent of the KVC which underlies the $\alpha$–$\gamma$ phase transition in elemental Ce [18]. The phase transition in Ce is characterized by a strong increase of the Kondo temperature concomitant with a volume collapse under pressure or upon cooling [31, 32]. This motivates us to attempt a description of the temperature-induced changes of the properties of golden Sm$_{1-x}$Y$_x$S using the KVC.
FIG. 2. (A) Temperature dependence of the Sm-L_{3} PFY-XAS spectra for b–SmS, b–Sm_{0.83}Y_{0.17}S, g–Sm_{0.83}Y_{0.17}S and g–Sm_{0.67}Y_{0.33}S, respectively. The dashed lines display the best fit to the base temperature data. (B) Temperature and doping dependence of the Sm valence.

THEORY

The physics of the KVC can be modeled by a Kondo lattice Hamiltonian, where the Anderson lattice Hamiltonian, $H_{AL}$, is extended by $H_{lat}$ that describes the coupling between $f$-hybridization, $\Gamma$, and the local strain $\varepsilon_i$ [34]:

$$H_{lat} = -\gamma \sum_{i,s} \varepsilon_i (f_{i,s}^{\dagger} c_{i,s} + h.c) + \frac{B}{2N_0} \sum_i \varepsilon_i^2.$$  \hspace{1cm} (1)

$\gamma$ describes the linear volume dependence of the hybridization, $B$ is the bare bulk modulus, $N_0$ is a reference volume and $N_0$ denotes the number of unit cells in the system. $f_{i,s}^{\dagger}$ and $c_{i,s}^{\dagger}$ are the annihilation (creation) operators of an $f$- and conduction electron at position $i$ with spin $s$. Using a slave boson mean-field theory the following equation of state for the Kondo lattice model is derived [34]:

$$p(\varepsilon) = -B \varepsilon - 2\gamma (\varepsilon_f - \varepsilon_f^0)(1 - n_f)$$

$$\frac{1}{1 - \gamma \varepsilon}.$$  \hspace{1cm} (2)

Here, $\varepsilon_f^0$ and $\varepsilon_f$ are the bare and renormalized $f$-electron energy, respectively and $\varepsilon = (V - V_0)/V_0$. The equation of state shows that the Kondo contribution to the pressure is negative if $\gamma$ is positive. We display $p(\varepsilon)$ in Fig. 3A for various reduced temperatures $T/D$, where $D$ is the conduction electron band width. The curves show the archetypal liquid-gas volume contraction under compression, which is strongly reminiscent of the $\alpha$-$\gamma$ KVC in Ce [18 32 33]. This indicates that the equation of state of Sm_{1-x}Y_xS properly describes the first-order volume collapse induced by chemical pressure, where the critical pressure corresponds to the critical Y concentration $x=0.17$ at the black-to-gold transition.

Strikingly, the pressure-volume curves displayed in Fig. 3B also show that a decrease in the temperature results in an increase of the volume of the system, as highlighted by the black arrow. This volume expansion reaches a first-order transition for a critical temperature $T_C$. Moreover, minimizing the slave boson mean-field free-energy with respect to $n_f$ also leads to a first-order valence transition at $T_C$ (see Fig. 3B).

The first-order nature of the temperature-induced phase transition derived from these thermodynamic calculations is in stark contrast with the experimental observations of a continuous transition. However, the Kondo lattice model neglects the effect of disorder, which is a known characteristic of samples with substituted elements. A dilution of the Kondo effect can be modeled by a phenomenological two-fluid model, where two coexisting contributions of either residual local moments (fluid 1) or hybridized $f$-electrons (fluid 2) are assumed [19 55]. A local order parameter, $f(T-T_C)$, allows to control how the volume fraction between the two fluids evolves as a function of temperature. A first-order transition that is broadened by a gradient of local disorder can be described by $f(T) = [1 + \tanh(T/\sigma T_C)]/2$. Thus, the temperature and doping dependence of the valence $v$ for our case reads:

$$v(x, T) = [x v_{imp} + (1 - x) v_{lat,HT}] f(T - T_C)$$

$$v_{lat,LT} f(T_C - T).$$  \hspace{1cm} (3)

Here, $v_{imp} = 2.56$ denotes the Sm valence in the completely diluted alloy (limit at large Y concentrations) and $v_{lat,HT}$ and $v_{lat,LT}$ are the Kondo lattice contributions at high ($T \gg T_C$) and low ($T \ll T_C$) temperatures. Since Sm_{1-x}Y_xS retains a temperature-independent mixed state for $x = 0$, we set $v_{lat,LT} = v_{lat,HT} = 2.19$. Best agreements to the experimental results at $x = 0.17$ and $0.33$ were found for a broadening
**FIG. 3.** (A) KVC equation of state for various reduced temperatures $T/D$. (B) and (C) Temperature dependent first-order valence and volume transitions at pressures $p_1 < p_2$.

**FIG. 4.** Fit of the experimental data (circles) with the two-fluid model (dashed line) $v(x, T) = [x v_{\text{imp}} + (1-x) v_{\text{lat,HT}}] f(T-T_C) + v_{\text{lat,LT}} f(T_C-T)$ with $v_{\text{imp}} = 2.56$, $v_{\text{lat,HT}} = v_{\text{lat,LT}} = 2.19$ and $f(T) = [1 + \tanh(T/T_C \sigma)]/2$ with $\sigma \sim 6.2$.

factor $\sigma \sim 6.2$ and are shown in Fig. 4 with $T_C = 145$ and 150 K, respectively.

**DISCUSSION**

This theoretical analysis of our experimental data strongly suggests that the electronic phase transitions in Sm$_{1-x}$Y$_x$S, both as a function of doping and temperature, arise from a KVC mechanism. Due to local disorder in the Y concentration the first-order character of the temperature-induced transition in golden SmS smears out macroscopically, leading to a continuous NTE over a $\sim 200$ K range. The NTE is therefore enabled in this material through a combination of the Kondo screening of the local Sm 4$f$ spins provoking an increase of the 4$f$-occupancy and the strong coupling between the electronic and lattice degrees of freedom.

This scenario is in contrast with another theoretical model which assigns the phase transitions in SmS to an excitonic instability [38–40]. The excitonic model predicts that compression leads to the softening of a bound electron-hole state, which ultimately condensates into the ground state at the black-to-gold transition. It is further claimed that in the golden phase the same exciton gaps out at low temperatures, triggering a pseudo-gap structure with semimetallic properties. However, we note that disorder induced into the system by the Y substitution is expected to impede the formation of a coherent excitonic wave-function, as a randomly distributed impurity potential locally breaks bound electron-hole pairs. Thus, a scenario based on exciton condensation is unlikely to explain the behavior in Y-doped SmS. It is also noted that a recent DMFT study used a conventional broad Kondo crossover to describe the low-temperature behavior of golden SmS [16], but neglected the coupling to the crystal lattice. In our model it is this electron-lattice coupling that gives rise to a unified mechanism underpinning the pressure and temperature-induced volume collapses, and the associated giant NTE in the golden phase.

Finally, we discuss the possibility to find giant NTE in other Kondo materials which are expected to show a valence decrease at low temperatures. Suitable candidates are limited to Sm, Tm, and Yb-based materials for lanthanides. While our results indicate that the proximity and, eventually, the coupling to a structural instability is a key ingredient, the example given by the large first-order valence decrease in YbInCu$_4$ at low temperatures can offer insight into the coupling of the Kondo effect to an electronic instability [41]. In this system, despite a decrease of the valence by an amount nearly as large as $g-$Sm$_{0.83}$Y$_{0.17}$S ($\Delta n_f=0.16$), the volume change is ten time smaller, at 0.5%. This stresses the importance of the coupling between the Kondo effect and the lattice to generate a large NTE. Further, the weaker magnitude of the transition in SmB$_6$ suggests that the relative number of rare-earth ions per unit cell needs to be large enough for
the expansion of the ionic radius to have a sizeable effect on the lattice and provoke a volume collapse. This suggests that a combination of strong electron-lattice coupling and a large number of rare-earth ions per unit cell are both necessary ingredients to Kondo-induced NTE.

CONCLUSION

We have studied the structural and electronic properties of Sm$_{1-x}$Y$_x$S to identify the mechanism behind its giant isotropic NTE at $x \geq 0.17$. We find that it is directly linked to a massive decrease in the Sm valence, providing evidence for a strong coupling between the electronic and lattice degrees of freedom. A treatment of the experimental results in the KVC and twofluid models provides a natural explanation for the instabilities induced by chemical pressure and temperature. In this scenario the temperature-induced volume collapse is broadened by chemical disorder, leading to a continuous NTE over 200 K. This study shows the potential of Kondo lattice materials for practical applications requiring tunable, isotropic NTE.

Materials and Methods

Single crystals with Y concentrations $x = 0, 0.05, 0.17$ and 0.33 synthesized by the Bridgman method. Crystals with $x = 0.17$ are either black or golden, which signifies that the semiconductor-to-metal transition occurs very close to this nominal yttrium concentration.

High-resolution X-ray absorption spectroscopy was performed at the Sm L$_3$-edge in the partial fluorescence yield mode (PFY-XAS) by monitoring the intensity emitted over a 1 eV window around the maximum of the L$_0$$_1$ emission line while scanning the incident energy through the Sm L$_3$ edge. The experiment was carried out at the Taiwan beamline BL12XU in SPring-8 using the same experimental setup as in Ref. [20], and using a similar setup at the GALAXIES beamline at the SOLEIL synchrotron [43, 44]. Each spectrum was fitted to three Gaussian contributions in order to satisfy for the transitions to the continuum. As discussed in detail in Ref. [20], the divalent component requires a fit of three Gaussian contributions in order to satisfactorily reproduce the preshoulder A, the main peak B and the high-energy shoulder C, arising from crystal-field split 5$d$ $t_{2g}$ and $e_g$ subbands. The exact Sm valence is derived from the relative intensity between the divalent and trivalent peak.

X-ray power diffraction measurements were performed at the 28-ID-1 beamline at NSLS-II. The unit cell volumes were refined in space group $Fm\bar{3}m$ as a function of temperature by means of a Rietveld and Le Bail analysis using the GSAS-II software [45].

All data needed to evaluate the conclusions in the paper are present in the paper. Additional data related to this paper may be requested from the authors. Correspondence and requests for materials should be addressed either to D. G. M. or to I. J. (E-mail: dmazzone@bnl.gov or jarrige@bnl.gov).

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